

Data sheet acquired from Harris Semiconductor

CD54HC688, CD74HC688, CD54HCT688, CD74HCT688

High-Speed CMOS Logic 8-Bit Magnitude Comparator

September 1997 - Revised August 2003

Features

- Cascadable
- Fanout (Over Temperature Range)
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility,
 V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $I_I \le 1\mu A$ at V_{OL} , V_{OH}

Description

The 'HC688 and 'HCT688 are 8-bit magnitude comparators designed for use in computer and logic applications that require the comparison of two 8-bit binary words. When the compared words are equal the output (Y) is low and can be used as the enabling input for the next device in a cascaded application.

Ordering Information

| PART NUMBER | TEMP. RANGE (°C) | PACKAGE |
|---------------|------------------|--------------|
| CD54HC688F3A | -55 to 125 | 20 Ld CERDIP |
| CD54HCT688F3A | -55 to 125 | 20 Ld CERDIP |
| CD74HC688E | -55 to 125 | 20 Ld PDIP |
| CD74HC688M | -55 to 125 | 20 Ld SOIC |
| CD74HC688M96 | -55 to 125 | 20 Ld SOIC |
| CD74HC688NSR | -55 to 125 | 20 Ld SOP |
| CD74HC688PWR | -55 to 125 | 20 Ld TSSOP |
| CD74HC688PWT | -55 to 125 | 20 Ld TSSOP |
| CD74HCT688E | -55 to 125 | 20 Ld PDIP |
| CD74HCT688M | -55 to 125 | 20 Ld SOIC |
| CD74HCT688M96 | -55 to 125 | 20 Ld SOIC |

NOTE: When ordering, use the entire part number. The suffixes 96 and R denote tape and reel. The suffix T denotes a small-quantity reel of 250.

Pinout

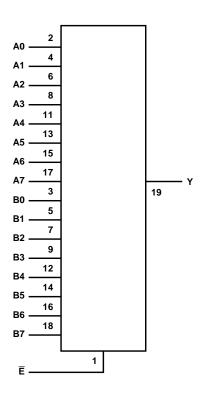
CD54HC688, CD54HCT688 (CERDIP) CD74HC688 (PDIP, SOIC, SOP, TSSOP) CD74HCT688 (PDIP, SOIC) TOP VIEW

> 20 V_{CC} E 1 Α0 2 19 Y B0 18 B7 Α1 17 A7 16 B6 15 A6 14 B5 **B2** 13 A5 А3 8 12 B4 B3 9

> > 11 A4

GND

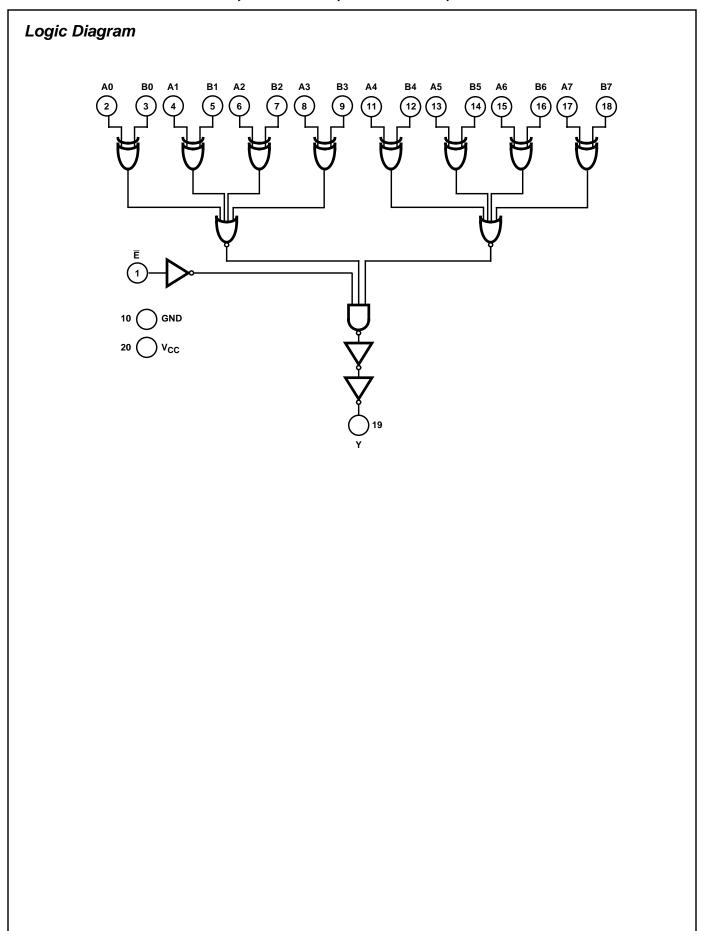
Functional Diagram



TRUTH TABLE

| INP | итѕ | OUPUTS |
|-------|-----|--------|
| A, B | Ē | Y |
| A = B | L | L |
| A≠B | L | Н |
| X | Н | Н |

H = High Voltage Level, L = Low Voltage Level, X = Don't Care



$\begin{tabular}{ll} \textbf{Absolute Maximum Ratings} \\ DC Supply Voltage, V_{CC} ... -0.5V to 7V \\ DC Input Diode Current, I_{IK} \\ For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$... <math>\pm 20\text{mA}$ \\ DC Output Diode Current, I_{OK} \\ For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$... <math>\pm 20\text{mA}$ \\ DC Output Source or Sink Current per Output Pin, I_O \\ For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$... <math>\pm 25\text{mA}$ \\ DC V_{CC} or Ground Current, I_{CC} or I_{GND} ... <math>\pm 50\text{mA}$ \\ \end{tabular}$

Thermal Information

| Thermal Resistance (Typical, Note 1) | θ_{JA} (°C/W) |
|--|----------------------|
| E (PDIP) Package | 69 |
| M (SOIC) Package | 58 |
| NSR (SOP) Package | 60 |
| PW (TSSOP) Package | 83 |
| Maximum Junction Temperature | |
| Maximum Storage Temperature Range | 65°C to 150°C |
| Maximum Lead Temperature (Soldering 10s) | 300°C |
| (SOIC - Lead Tips Only) | |

Operating Conditions

| Temperature Range (T _A)55°C to 125°C |
|---|
| Supply Voltage Range, V _{CC} |
| HC Types2V to 6V |
| HCT Types |
| DC Input or Output Voltage, V _I , V _O |
| Input Rise and Fall Time |
| 2V |
| 4.5V 500ns (Max) |
| 6V |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

| | | TE: CONDI | | Vcc | V _{CC} 25°C | | | -40°C TO 85°C | | -55°C TO 125°C | | |
|-----------------------------|-----------------|------------------------------------|---------------------|-----|----------------------|-----|------|---------------|------|----------------|------|-------|
| PARAMETER | SYMBOL | V _I (V) | I _O (mA) | (V) | MIN | TYP | MAX | MIN | MAX | MIN | MAX | UNITS |
| HC TYPES | | | | | | | | | | | | |
| High Level Input | V _{IH} | - | - | 2 | 1.5 | - | - | 1.5 | - | 1.5 | - | V |
| Voltage | | | | 4.5 | 3.15 | - | - | 3.15 | - | 3.15 | - | V |
| | | | | 6 | 4.2 | - | - | 4.2 | - | 4.2 | - | V |
| Low Level Input | V _{IL} | - | - | 2 | - | - | 0.5 | - | 0.5 | - | 0.5 | V |
| Voltage | | | | 4.5 | - | - | 1.35 | - | 1.35 | - | 1.35 | V |
| | | | | 6 | - | - | 1.8 | - | 1.8 | - | 1.8 | V |
| High Level Output | VoH | H VIH or VIL | -0.02 | 2 | 1.9 | - | - | 1.9 | - | 1.9 | - | V |
| Voltage CMOS Loads | | | -0.02 | 4.5 | 4.4 | - | - | 4.4 | - | 4.4 | - | V |
| OWOO LOAGS | | | -0.02 | 6 | 5.9 | - | - | 5.9 | - | 5.9 | - | V |
| High Level Output | 1 | | - | - | - | - | - | - | - | - | - | V |
| Voltage TTL Loads | | | -4 | 4.5 | 3.98 | - | - | 3.84 | - | 3.7 | - | V |
| TTE Edad3 | | | -5.2 | 6 | 5.48 | - | - | 5.34 | - | 5.2 | - | V |
| Low Level Output | V _{OL} | V _{IH} or V _{IL} | 0.02 | 2 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| Voltage CMOS Loads | | | 0.02 | 4.5 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| OWOO LOAGS | | | 0.02 | 6 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| Low Level Output | 1 | | - | - | - | - | - | - | - | - | - | V |
| Voltage TTL Loads | | | 4 | 4.5 | - | - | 0.26 | - | 0.33 | - | 0.4 | V |
| TIL LOGUS | | | 5.2 | 6 | - | - | 0.26 | - | 0.33 | - | 0.4 | V |
| Input Leakage Current | II | V _{CC} or GND | - | 6 | - | - | ±0.1 | - | ±1 | - | ±1 | μА |
| Quiescent Device Current | lcc | V _{CC} or GND | 0 | 6 | - | - | 8 | - | 80 | - | 160 | μА |

DC Electrical Specifications (Continued)

| | | TE: CONDI | _ | vs v _{cc} | | 25°C | | | -40°C TO 85°C | | -55°C TO 125°C | |
|--|------------------------------|------------------------------------|---------------------|--------------------|------|------|------|------|---------------|-----|----------------|-------|
| PARAMETER | SYMBOL | V _I (V) | I _O (mA) | (S) | MIN | TYP | MAX | MIN | MAX | MIN | MAX | UNITS |
| HCT TYPES | | | | | | | | | | | | |
| High Level Input Voltage | V _{IH} | - | - | 4.5 to 5.5 | 2 | - | - | 2 | - | 2 | - | V |
| Low Level Input Voltage | V _{IL} | - | - | 4.5 to 5.5 | - | - | 0.8 | - | 0.8 | - | 0.8 | V |
| High Level Output Voltage CMOS Loads | Voн | V _{IH} or V _{IL} | -0.02 | 4.5 | 4.4 | - | - | 4.4 | - | 4.4 | - | V |
| High Level Output Voltage TTL Loads | | | -4 | 4.5 | 3.98 | - | - | 3.84 | - | 3.7 | - | V |
| Low Level Output Voltage CMOS Loads | V _{OL} | V _{IH} or V _{IL} | 0.02 | 4.5 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| Low Level Output Voltage TTL Loads | | | 4 | 4.5 | - | - | 0.26 | - | 0.33 | - | 0.4 | V |
| Input Leakage Current | lį | V _{CC} and GND | 0 | 5.5 | - | - | ±0.1 | - | ±1 | - | ±1 | μΑ |
| Quiescent Device Current | Icc | V _{CC} or GND | 0 | 5.5 | - | - | 8 | - | 80 | - | 160 | μА |
| Additional Quiescent Device Current Per Input Pin: 1 Unit Load | ΔI _{CC} (Note 2) | V _{CC} -2.1 | - | 4.5 to 5.5 | - | 100 | 360 | - | 450 | - | 490 | μΑ |

NOTE:

HCT Input Loading Table

| INPUT | UNIT LOADS |
|-------------|------------|
| Enable | 0.7 |
| Data Inputs | 0.35 |

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Table, e.g., 360µA max at $25^{o}C.$

Switching Specifications Input t_{r} , $t_{f} = 6 \text{ns}$

| | | TEST | TEST V _{CC} | | 25°C | | | -40°C TO 85°C | | -55°C TO 125°C | |
|------------------------------|-------------------|-----------------------|----------------------|-----|------|-----|-----|---------------|-----|----------------|-------|
| PARAMETER | SYMBOL | CONDITIONS | (V) | MIN | TYP | MAX | MIN | MAX | MIN | MAX | UNITS |
| HC TYPES | - | | | | | | - | - | - | - | |
| Propagation Delay (Figure 1) | t _{PLH,} | C _L = 50pF | 2 | - | - | 170 | - | 210 | - | 255 | ns |
| An to Output | t _{PHL} | | 4.5 | - | - | 34 | - | 42 | - | 51 | ns |
| | | C _L =15pF | 5 | - | 14 | - | - | - | - | - | ns |
| | | C _L = 50pF | 6 | - | - | 29 | - | 36 | - | 43 | ns |
| Bn to Output | t _{PLH,} | C _L = 50pF | 2 | - | - | 170 | - | 210 | - | 255 | ns |
| | t _{PHL} | | 4.5 | - | - | 34 | - | 42 | - | 51 | ns |
| | | C _L =15pF | 5 | - | 14 | - | - | - | - | - | ns |
| | | C _L = 50pF | 6 | - | - | 29 | - | 36 | - | 43 | ns |

^{2.} For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

Switching Specifications Input t_r , $t_f = 6ns$ (Continued)

| | | TEST | v _{cc} | | 25°C | | -40°C 1 | O 85°C | -55°C T | O 125°C | |
|--|-------------------------------------|-----------------------|-----------------|-----|------|-----|---------|--------|---------|---------|-------|
| PARAMETER | SYMBOL | CONDITIONS | (V) | MIN | TYP | MAX | MIN | MAX | MIN | MAX | UNITS |
| E to Output | t _{PLH} , | C _L = 50pF | 2 | - | - | 120 | - | 150 | - | 180 | ns |
| | t _{PHL} | | 4.5 | - | - | 24 | - | 30 | - | 36 | ns |
| | | C _L =15pF | 5 | - | 9 | - | - | - | - | - | ns |
| | | C _L = 50pF | 6 | - | - | 20 | - | 26 | - | 30 | ns |
| Output Transition Time | t _{TLH} , t _{THL} | C _L = 50pF | 2 | - | - | 75 | - | 95 | - | 110 | ns |
| (Figure 1) | | | 4.5 | - | - | 15 | - | 19 | - | 22 | ns |
| | | | 6 | - | - | 13 | - | 16 | - | 19 | ns |
| Input Capacitance | C _{IN} | C _L = 50pF | - | - | - | 10 | - | 10 | - | 10 | pF |
| Power Dissipation Capacitance (Notes 3, 4) | C _{PD} | C _L =15pF | 5 | - | 22 | - | - | - | - | - | pF |
| HCT TYPES | | | | | | • | | | | | |
| Propagation Delay (Figure 1) | t _{PLH} , | C _L = 50pF | 4.5 | - | - | 34 | - | 42 | - | 51 | ns |
| An to Output | t _{PHL} | C _L =15pF | 5 | - | 14 | - | - | - | - | - | ns |
| Bn to Output | t _{PLH,} | C _L = 50pF | 4.5 | - | - | 34 | - | 42 | - | 51 | ns |
| | t _{PHL} | C _L =15pF | 5 | - | 14 | - | - | - | - | - | ns |
| E to Output | t _{PLH,} | C _L = 50pF | 4.5 | - | - | 24 | - | 30 | - | 36 | ns |
| | ^t PHL | C _L =15pF | 5 | - | 9 | - | - | - | - | - | ns |
| Output Transition Time (Figure 1) | t _{TLH} , t _{THL} | C _L = 50pF | 4.5 | - | - | 15 | - | 19 | - | 22 | ns |
| Input Capacitance | C _{IN} | C _L = 50pF | - | - | - | 10 | - | 10 | - | 10 | pF |
| Power Dissipation Capacitance (Notes 3, 4) | C _{PD} | C _L =15pF | 5 | - | 22 | - | - | - | - | - | pF |

NOTES:

- 3. $C_{\mbox{\scriptsize PD}}$ is used to determine the dynamic power consumption, per gate.
- 4. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where $f_i = Input$ Frequency, $C_L = Output$ Load Capacitance, $V_{CC} = Supply$ Voltage.

Test Circuit and Waveform

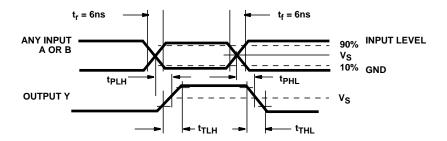


FIGURE 1. PROPAGATION DELAY AMD TRANSITION TIMES



PACKAGING INFORMATION

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | e Eco Plan ⁽²⁾ | Lead/Ball Finish | MSL Peak Temp (3) |
|------------------|-----------------------|-----------------|--------------------|------|----------------|---------------------------|------------------|--------------------|
| 5962-8685701RA | ACTIVE | CDIP | J | 20 | 1 | TBD | A42 SNPB | N / A for Pkg Type |
| CD54HC688F3A | ACTIVE | CDIP | J | 20 | 1 | TBD | A42 SNPB | N / A for Pkg Type |
| CD54HCT688F | ACTIVE | CDIP | J | 20 | 1 | TBD | A42 SNPB | N / A for Pkg Type |
| CD54HCT688F3A | ACTIVE | CDIP | J | 20 | 1 | TBD | A42 SNPB | N / A for Pkg Type |
| CD74HC688E | ACTIVE | PDIP | N | 20 | 20 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type |
| CD74HC688EE4 | ACTIVE | PDIP | N | 20 | 20 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type |
| CD74HC688M | ACTIVE | SOIC | DW | 20 | 25 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HC688M96 | ACTIVE | SOIC | DW | 20 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HC688M96E4 | ACTIVE | SOIC | DW | 20 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HC688M96G4 | ACTIVE | SOIC | DW | 20 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HC688ME4 | ACTIVE | SOIC | DW | 20 | 25 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HC688MG4 | ACTIVE | SOIC | DW | 20 | 25 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HC688NSR | ACTIVE | SO | NS | 20 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HC688NSRE4 | ACTIVE | SO | NS | 20 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HC688NSRG4 | ACTIVE | SO | NS | 20 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HC688PWR | ACTIVE | TSSOP | PW | 20 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HC688PWRE4 | ACTIVE | TSSOP | PW | 20 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HC688PWRG4 | ACTIVE | TSSOP | PW | 20 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HC688PWT | ACTIVE | TSSOP | PW | 20 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HC688PWTE4 | ACTIVE | TSSOP | PW | 20 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HC688PWTG4 | ACTIVE | TSSOP | PW | 20 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HCT688E | ACTIVE | PDIP | N | 20 | 20 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type |
| CD74HCT688EE4 | ACTIVE | PDIP | N | 20 | 20 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type |
| CD74HCT688M | ACTIVE | SOIC | DW | 20 | 25 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HCT688M96 | ACTIVE | SOIC | DW | 20 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HCT688M96E4 | ACTIVE | SOIC | DW | 20 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HCT688M96G4 | ACTIVE | SOIC | DW | 20 | 2000 | Green (RoHS & | CU NIPDAU | Level-1-260C-UNLIM |



PACKAGE OPTION ADDENDUM

9-Oct-2007

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | | ckage Qty | Eco Plan ⁽²⁾ | Lead/Ball Finish | MSL Peak Temp ⁽³⁾ |
|------------------|-----------------------|-----------------|--------------------|----|--------------|----------------------------|------------------|------------------------------|
| | | | | | | no Sb/Br) | | |
| CD74HCT688ME4 | ACTIVE | SOIC | DW | 20 | 25 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| CD74HCT688MG4 | ACTIVE | SOIC | DW | 20 | 25 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL INFORMATION





| | Dimension designed to accommodate the component width |
|----|---|
| | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|-----------------|--------------------|----|------|--------------------------|--------------------------|---------|---------|---------|------------|-----------|------------------|
| CD74HC688M96 | SOIC | DW | 20 | 2000 | 330.0 | 24.4 | 10.8 | 13.0 | 2.7 | 12.0 | 24.0 | Q1 |
| CD74HC688PWR | TSSOP | PW | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.1 | 1.6 | 8.0 | 16.0 | Q1 |
| CD74HCT688M96 | SOIC | DW | 20 | 2000 | 330.0 | 24.4 | 10.8 | 13.0 | 2.7 | 12.0 | 24.0 | Q1 |





*All dimensions are nominal

| 7 th difficition and from that | | | | | | | |
|--------------------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
| CD74HC688M96 | SOIC | DW | 20 | 2000 | 346.0 | 346.0 | 41.0 |
| CD74HC688PWR | TSSOP | PW | 20 | 2000 | 346.0 | 346.0 | 33.0 |
| CD74HCT688M96 | SOIC | DW | 20 | 2000 | 346.0 | 346.0 | 41.0 |

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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